



TR 918F-1790-12

Medium Frequency Thyristor

Properties

- Amplifying gate
- High operational capability
- Optimized turn-on and turn-off parameters
- High operating frequency

Applications

- Power switching applications

Key Parameters

V_{DRM}, V_{RRM}	= 1 200	V
I_{TAV}	= 1 779	A
I_{TSM}	= 22.0	kA
V_{TO}	= 1.374	V
r_T	= 0.094	m Ω
t_q	= 10.0	μ s

Types

	V_{RRM}, V_{DRM}
TR 918F-1790-12	1 200 V
TR 918F-1790-10	1 000 V
TR 918F-1790-08	800 V
Conditions: $T_j = -40 \div 125$ °C, half sine waveform, $f = 50$ Hz, note 1	

Mechanical Data

F_m	Mounting force	22 ± 2 kN
m	Weight	0.48 kg
D_s	Surface creepage distance	25 mm
D_a	Air strike distance	13 mm

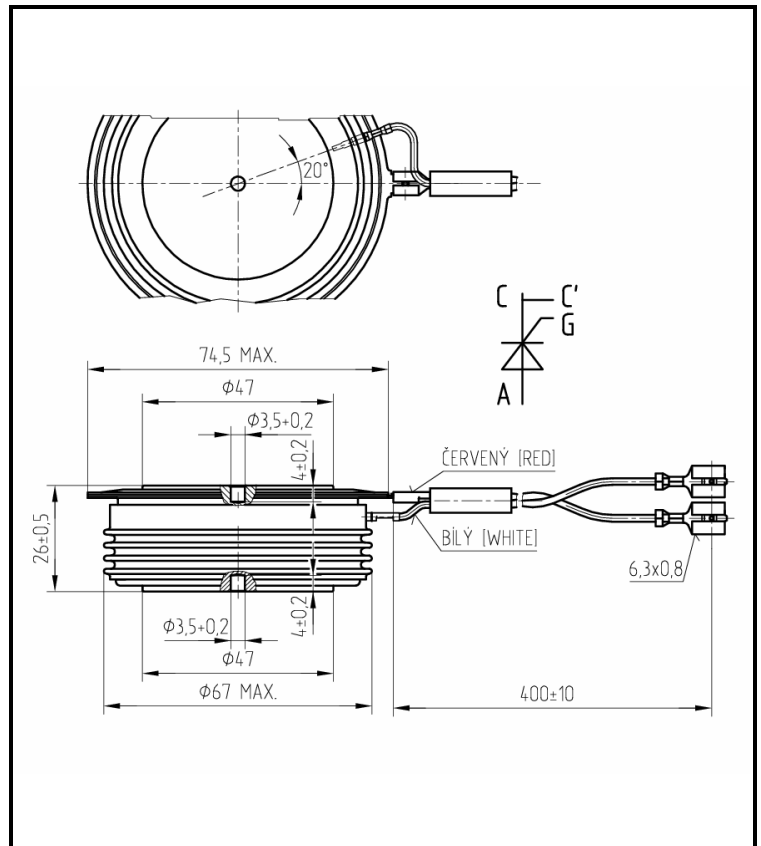


Fig. 1 Case

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Maximum Ratings			Maximum Limits	Unit
V_{RRM} V_{DRM}	Repetitive peak reverse and off-state voltage $T_j = -40 \div 125 \text{ }^\circ\text{C}$, note 1	TR 918F-1790-12 TR 918F-1790-10 TR 918F-1790-08	1 200 1 000 800	V
I_{TRMS}	RMS on-state current $T_c = 70 \text{ }^\circ\text{C}$, half sine waveform, $f = 50 \text{ Hz}$		2 794	A
I_{TAVm}	Average on-state current $T_c = 70 \text{ }^\circ\text{C}$, half sine waveform, $f = 50 \text{ Hz}$		1 779	A
I_{TSM}	Peak non-repetitive surge half sine pulse, $V_R = 0 \text{ V}$	$t_p = 10 \text{ ms}$ $t_p = 8.3 \text{ ms}$	22 000 23 500	A
$\dot{I}t$	Limiting load integral half sine pulse, $V_R = 0 \text{ V}$	$t_p = 10 \text{ ms}$ $t_p = 8.3 \text{ ms}$	2 420 000 2 292 000	A ² s
$(di_T/dt)_{cr}$	Critical rate of rise of on-state current $I_T = I_{TAVm}$, half sine waveform, $f = 50 \text{ Hz}$, $V_D = 2/3 V_{DRM}$, $t_r = 0.3 \mu\text{s}$, $I_{GT} = 2 \text{ A}$		800	A/ μs
$(dv_D/dt)_{cr}$	Critical rate of rise of off-state voltage $V_D = 2/3 V_{DRM}$		1 000	V/ μs
P_{GAVm}	Maximum average gate power losses		3	W
I_{FGM}	Peak gate current		10	A
V_{FGM}	Peak gate voltage		12	V
V_{RGM}	Reverse peak gate voltage		10	V
$T_{jmin} - T_{jmax}$	Operating temperature range		-40 \div 125	$^\circ\text{C}$
$T_{stgmin} - T_{stgmax}$	Storage temperature range		-40 \div 125	$^\circ\text{C}$

Unless otherwise specified $T_j = 125 \text{ }^\circ\text{C}$

Note 1: De-rating factor of 0.13% V_{RRM} or V_{DRM} per $^\circ\text{C}$ is applicable for T_j below $25 \text{ }^\circ\text{C}$

Characteristics		Value			Unit
		min.	typ.	max.	
V_{TM}	Maximum peak on-state voltage $I_{TM} = 2\ 000\ A$			1.560	V
V_{T0}	Threshold voltage			1.374	V
r_T	Slope resistance $I_{T1} = 2\ 812\ A, I_{T2} = 8\ 435\ A$			0.094	m Ω
I_{DM}	Peak off-state current $V_D = V_{DRM}$			100	mA
I_{RM}	Peak reverse current $V_R = V_{RRM}$			100	mA
t_{gd}	Delay time $T_j = 25\ ^\circ C, V_D = 0.4\ V_{DRM}, I_{TM} = I_{TAVM},$ $t_r = 0.3\ \mu s, I_{GT} = 2\ A$			2.0	μs
t_{q1}	Turn-off time $I_T = 1\ 000\ A, di_T/dt = -50\ A/\mu s,$ $V_R = 100\ V, V_D = 2/3\ V_{DRM},$ $dv_D/dt = 50\ V/\mu s$	group of t_q C D E		10.0 12.5 16.0	μs
Q_{rr}	Recovery charge the same conditions as at t_{q1}			380	μC
I_{rrM}	Reverse recovery current the same conditions as at t_{q1}			130	A
I_H	Holding current	$T_j = 25\ ^\circ C$ $T_j = 125\ ^\circ C$		250 150	mA
I_L	Latching current	$T_j = 25\ ^\circ C$ $T_j = 125\ ^\circ C$		1 500 1 000	mA
V_{GT}	Gate trigger voltage $V_D = 12V, I_T = 4\ A$	$T_j = -40\ ^\circ C$ $T_j = 25\ ^\circ C$ $T_j = 125\ ^\circ C$	0.25	4 3 2	V
I_{GT}	Gate trigger current $V_D = 12V, I_T = 4\ A$	$T_j = -40\ ^\circ C$ $T_j = 25\ ^\circ C$ $T_j = 125\ ^\circ C$	10	1000 500 300	mA

Unless otherwise specified $T_j = 125\ ^\circ C$

Thermal Parameters		Value	Unit
R_{thjc}	Thermal resistance junction to case <i>double side cooling</i>	16.0	K/kW
	<i>anode side cooling</i>	25.0	
	<i>cathode side cooling</i>	45.0	
R_{thch}	Thermal resistance case to heatsink <i>double side cooling</i>	4.0	K/kW
	<i>single side cooling</i>	8.0	

Transient Thermal Impedance																								
<p>Analytical function for transient thermal impedance</p> $Z_{thjc} = \sum_{i=1}^4 R_i (1 - \exp(-t/\tau_i))$ <p>Conditions: $F_m = 22 \pm 2$ kN, Double side cooled</p> <p>Correction for periodic waveforms</p> <table border="1"> <tr> <td>180° sine:</td> <td>add 1.3 K/kW</td> </tr> <tr> <td>180° rectangular:</td> <td>add 1.8 K/kW</td> </tr> <tr> <td>120° rectangular:</td> <td>add 3.0 K/kW</td> </tr> <tr> <td>60° rectangular:</td> <td>add 5.1 K/kW</td> </tr> </table>	180° sine:	add 1.3 K/kW	180° rectangular:	add 1.8 K/kW	120° rectangular:	add 3.0 K/kW	60° rectangular:	add 5.1 K/kW	<table border="1"> <thead> <tr> <th>i</th> <th>1</th> <th>2</th> <th>3</th> <th>4</th> </tr> </thead> <tbody> <tr> <td>τ_i (s)</td> <td>0.4653</td> <td>0.1533</td> <td>0.0375</td> <td>0.0034</td> </tr> <tr> <td>R_i (K/kW)</td> <td>5.50</td> <td>7.24</td> <td>2.00</td> <td>1.30</td> </tr> </tbody> </table> <p style="text-align: center;">Fig. 2 Dependence transient thermal impedance junction to case on square pulse</p>	i	1	2	3	4	τ_i (s)	0.4653	0.1533	0.0375	0.0034	R_i (K/kW)	5.50	7.24	2.00	1.30
180° sine:	add 1.3 K/kW																							
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On-State Characteristics

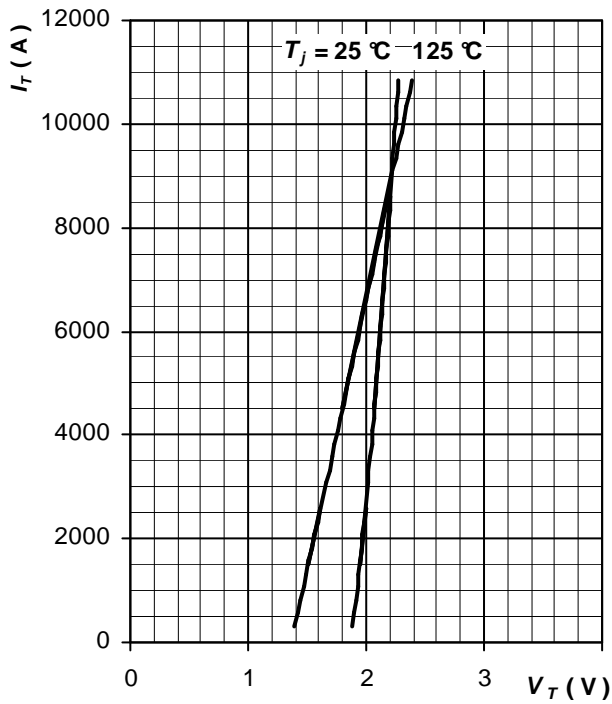


Fig. 3 Maximum on-state characteristics

Gate Trigger Characteristics

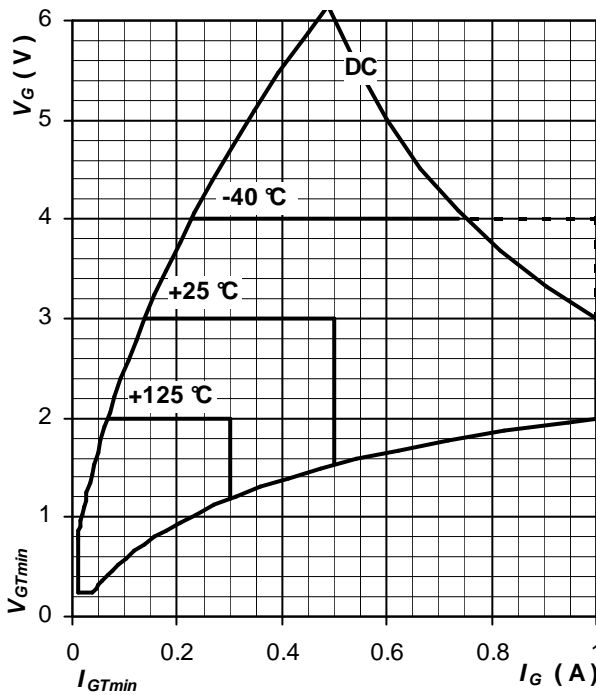


Fig. 4 Gate trigger characteristics

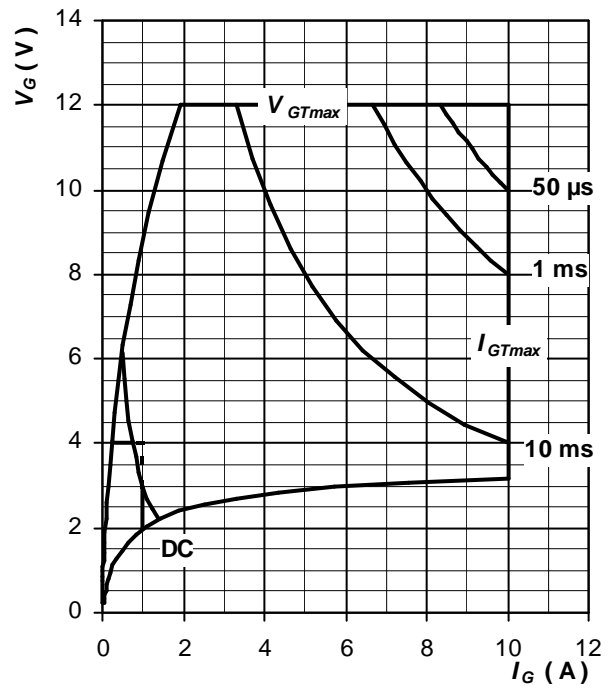


Fig. 5 Maximum peak gate power loss

Surge Characteristics

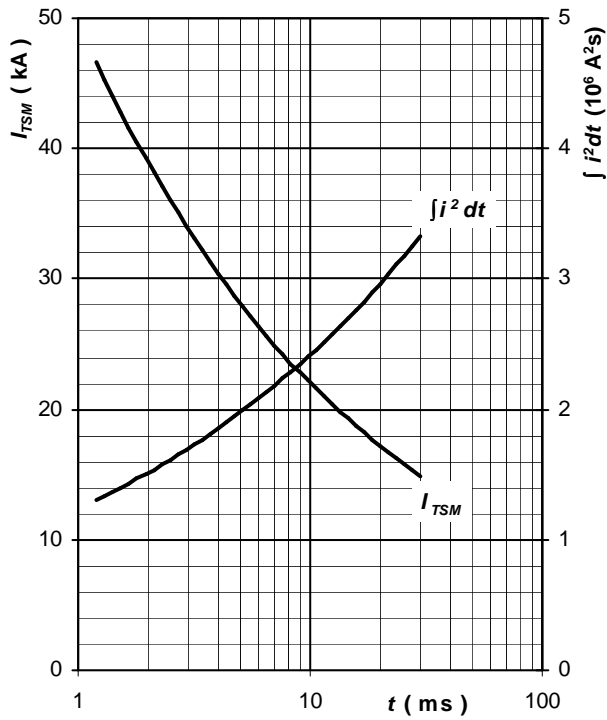


Fig. 6 Surge on-state current vs. pulse length, half sine wave, single pulse, $V_R = 0\text{ V}$, $T_j = T_{jmax}$

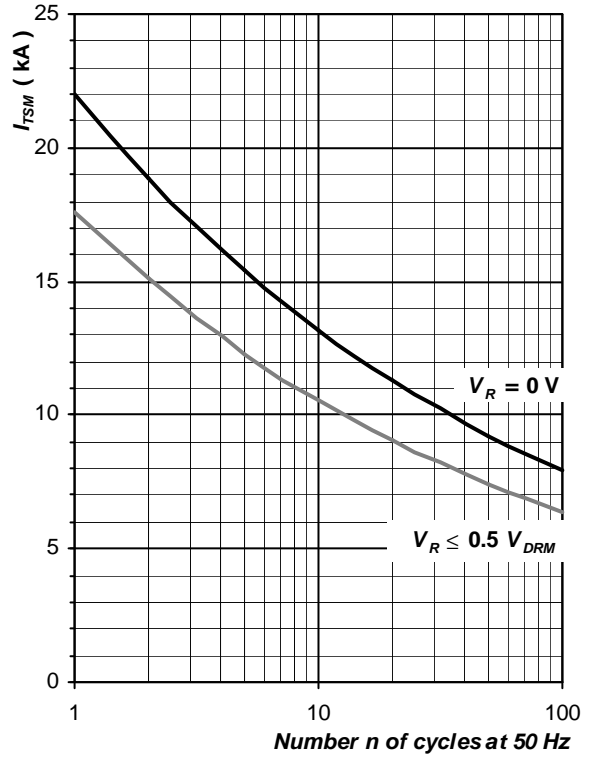


Fig. 7 Surge on-state current vs. number of pulses, half sine wave, $T_j = T_{jmax}$

Power Loss and Maximum Case Temperature Characteristics

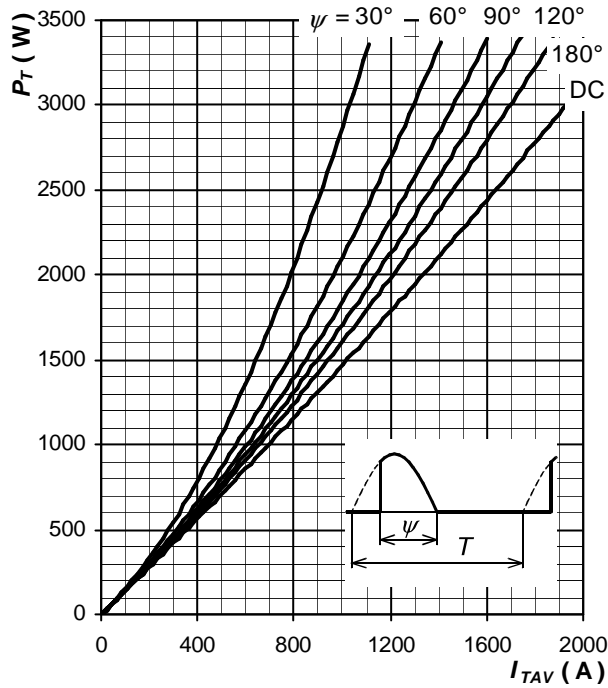


Fig. 8 On-state power loss vs. average on-state current, sine waveform, $f = 50$ Hz, $T = 1/f$

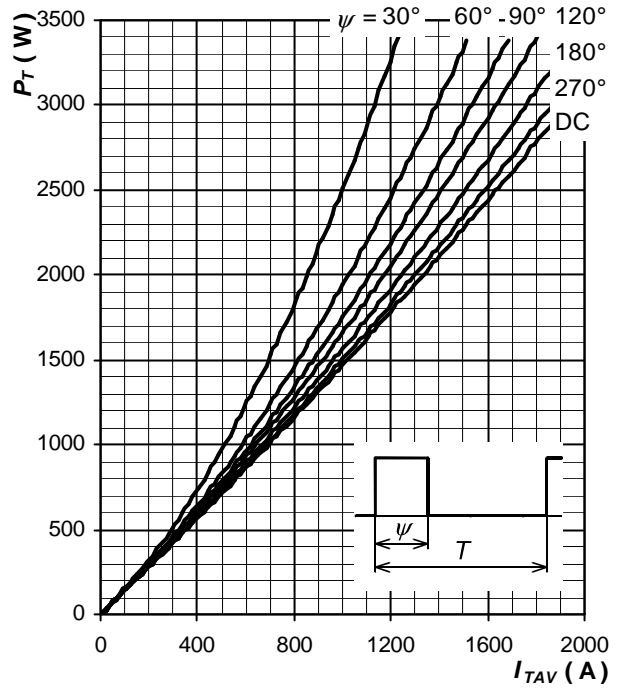


Fig. 9 On-state power loss vs. average on-state current, square waveform, $f = 50$ Hz, $T = 1/f$

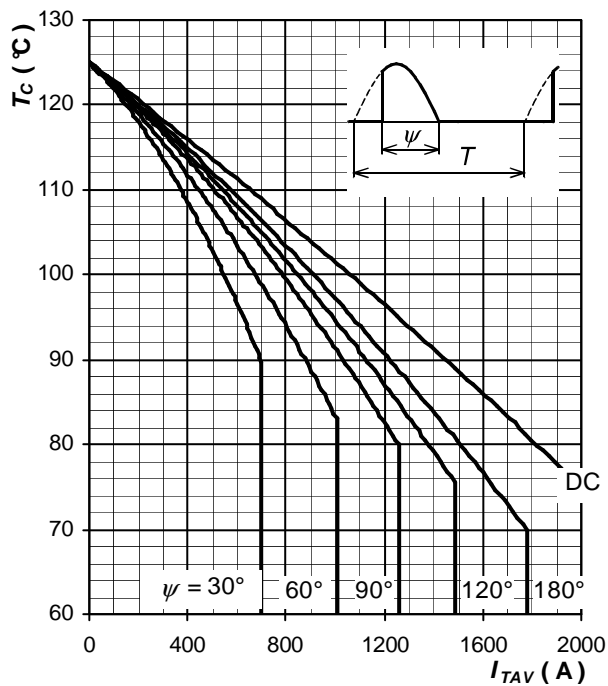


Fig. 10 Max. case temperature vs. aver. on-state current, sine waveform, $f = 50$ Hz, $T = 1/f$

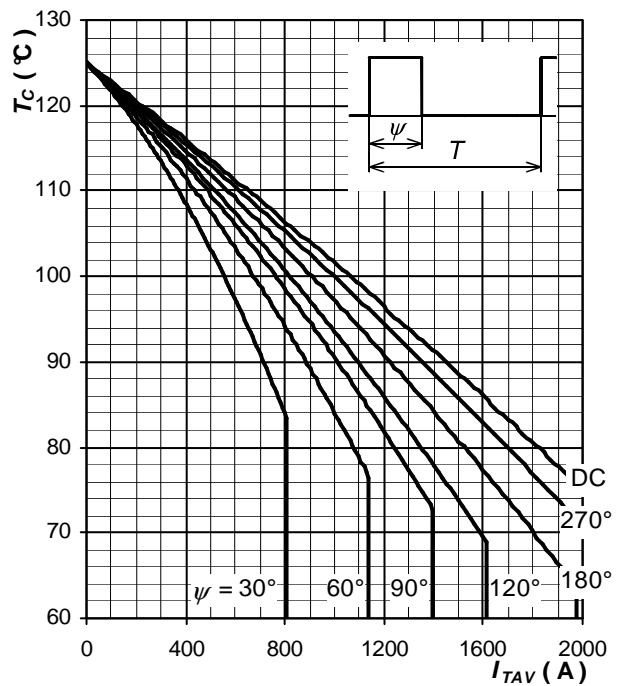


Fig. 11 Max. case temperature vs. aver. on-state current, square waveform, $f = 50$ Hz, $T = 1/f$

Note 2: Figures number 8 ÷ 11 have been calculated without considering any turn-on and turn-off losses. They are valid for $f = 50$ or 60 Hz operation.

Turn-off Time, Parameter Relationship

Maximum values of turn-off time at application specific conditions are given by using this formula:

$$t_q = t_{q1} \cdot \frac{t_q(T_j)}{t_{q1}} \cdot \frac{t_q(dv_D/dt)}{t_{q1}} \cdot \frac{t_q(-di_T/dt)}{t_{q1}}$$

where:

t_{q1} is turn-off time at standard conditions, see section "Characteristics"

$\frac{t_q(T_j)}{t_{q1}}$ is factor to be taken from fig. 12

$\frac{t_q(dv_D/dt)}{t_{q1}}$ is factor to be taken from fig. 13

$\frac{t_q(-di_T/dt)}{t_{q1}}$ is factor to be taken from fig. 14

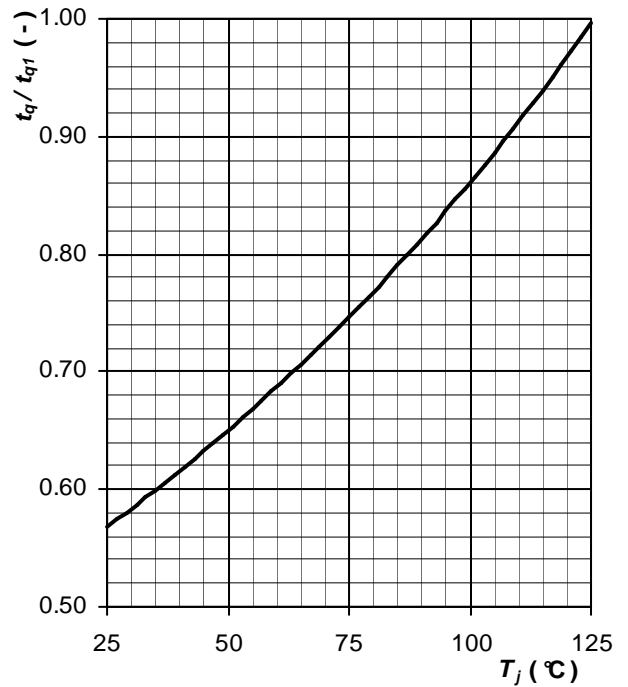


Fig. 12 Normalised maximum turn-off time vs. junction temperature

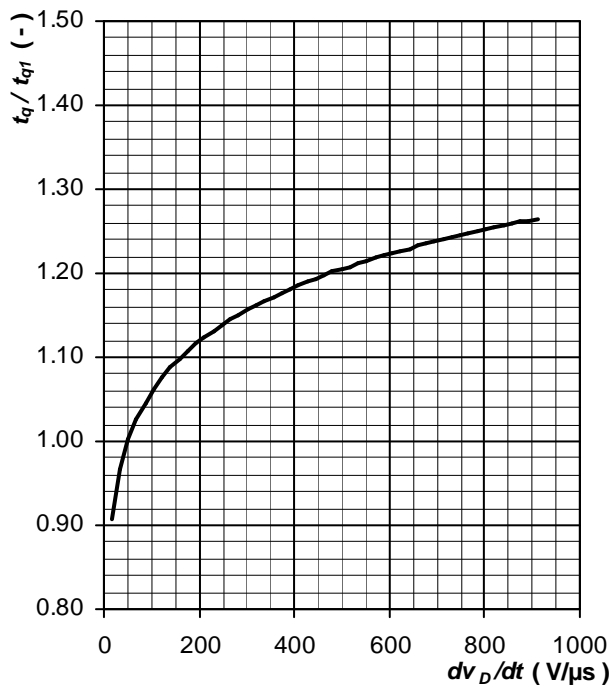


Fig. 13 Normalised maximum turn-off time vs. rate of rise of off-state voltage

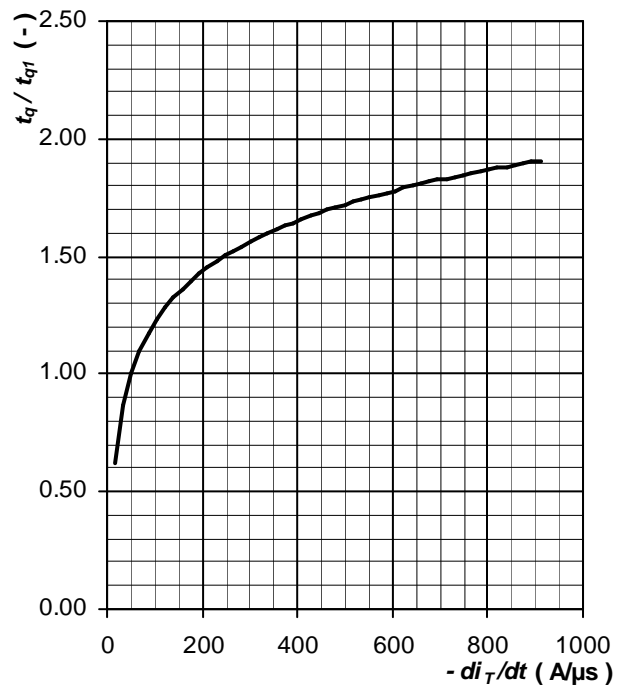


Fig. 14 Normalised maximum turn-off time vs. rate of fall of on-state current

Turn-on Characteristics

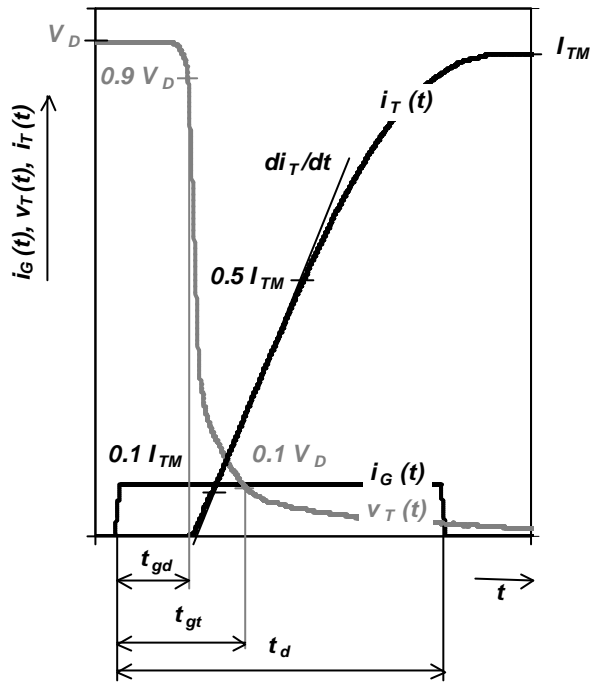


Fig. 15 Typical waveforms and definition of symbols at turn-on of a thyristor

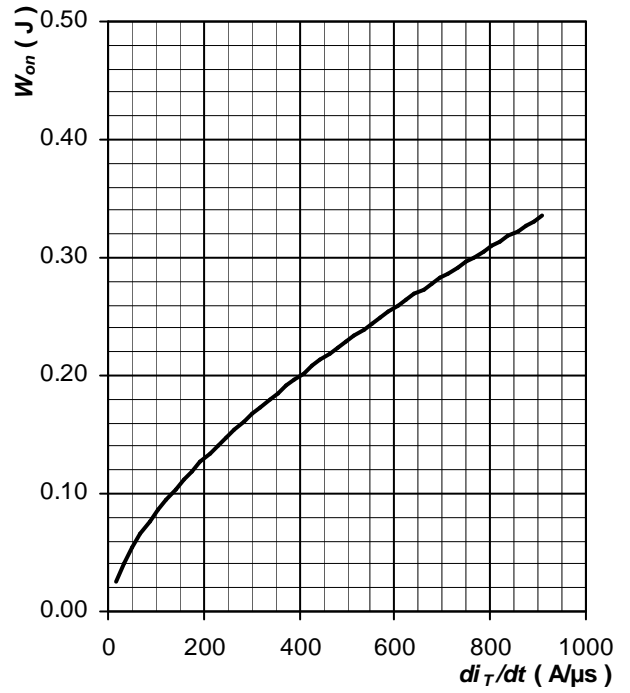


Fig. 16 Maximum turn-on energy per pulse vs. rate of rise on-state current, $T_j = T_{jmax}$

Turn-off Characteristics

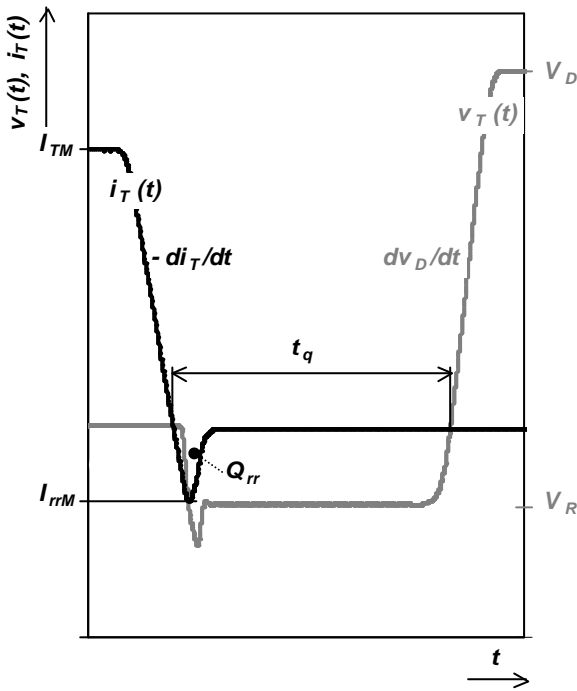


Fig. 17 Typical waveforms and definition of symbols at turn-off of a thyristor, inductive switching without RC snubber

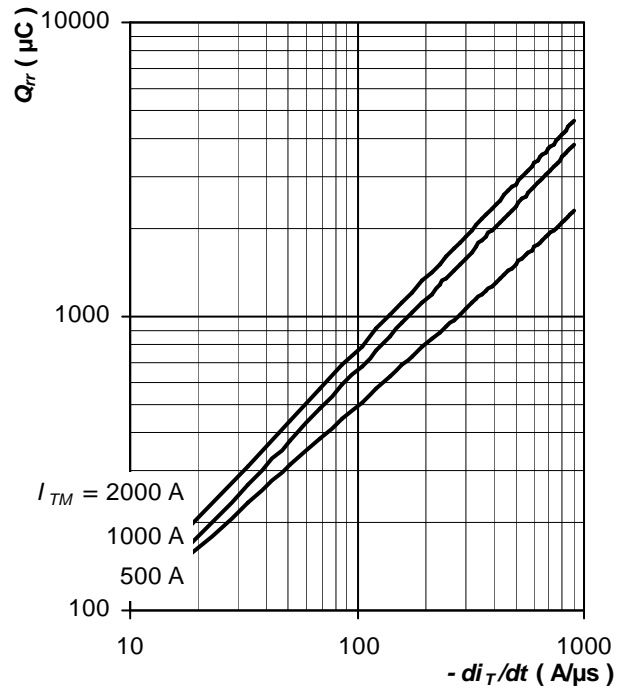


Fig. 18 Max. recovered charge vs. rate of fall on-state current, trapezoid pulse, $V_R = 100 \text{ V}$, $T_j = T_{jmax}$

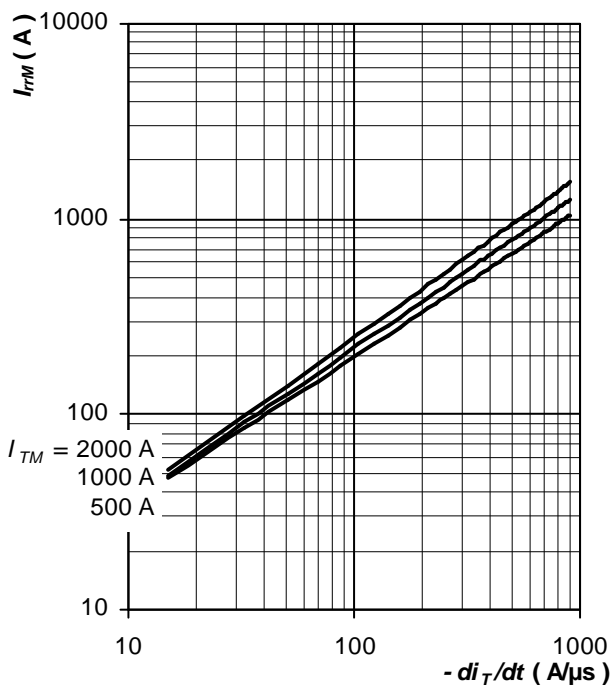


Fig. 19 Max. reverse recovery current vs. rate of fall on-state current, trapezoid pulse, $V_R = 100 \text{ V}$, $T_j = T_{jmax}$

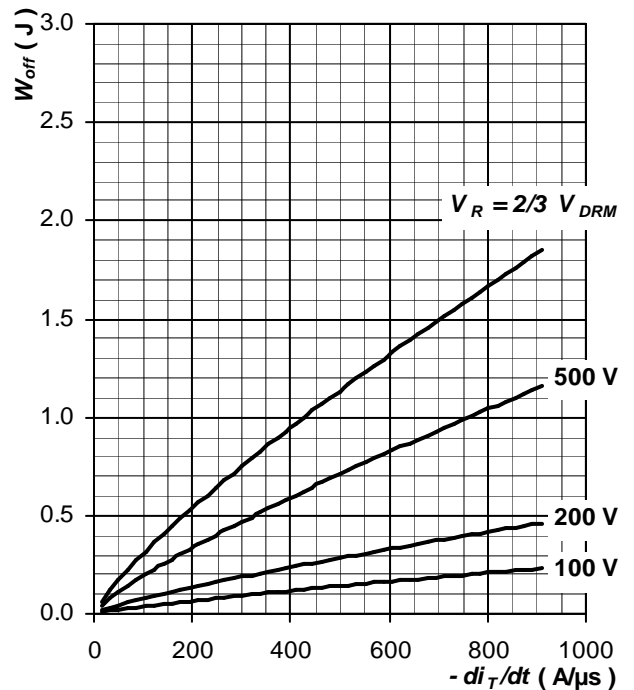


Fig. 20 Maximum turn-off energy per pulse vs. rate of fall on-state current, trapezoid pulse, inductive switching without RC snubber, $I_{TM} = 2000 \text{ A}$, $T_j = T_{jmax}$

Frequency Ratings

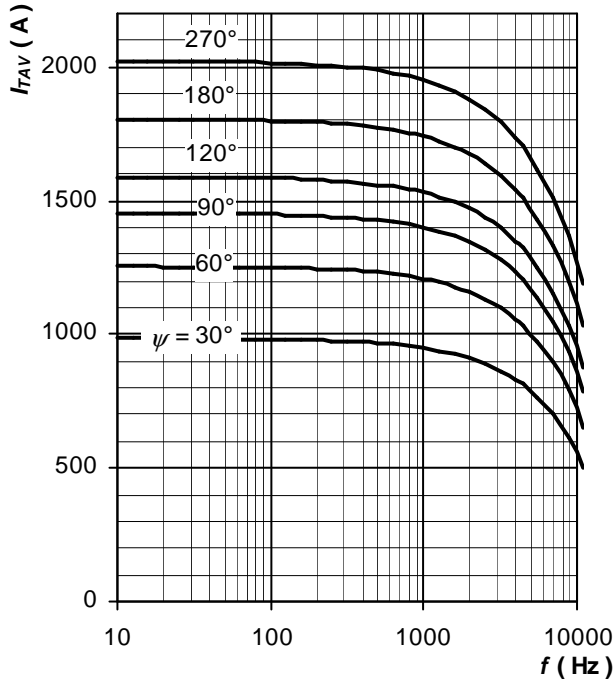


Fig. 21 Average on-state current vs. frequency, trapezoid waveform, $T_C = 70^\circ\text{C}$, $di_T/dt = \pm 100\text{ A}/\mu\text{s}$, $V_R = 100\text{ V}$

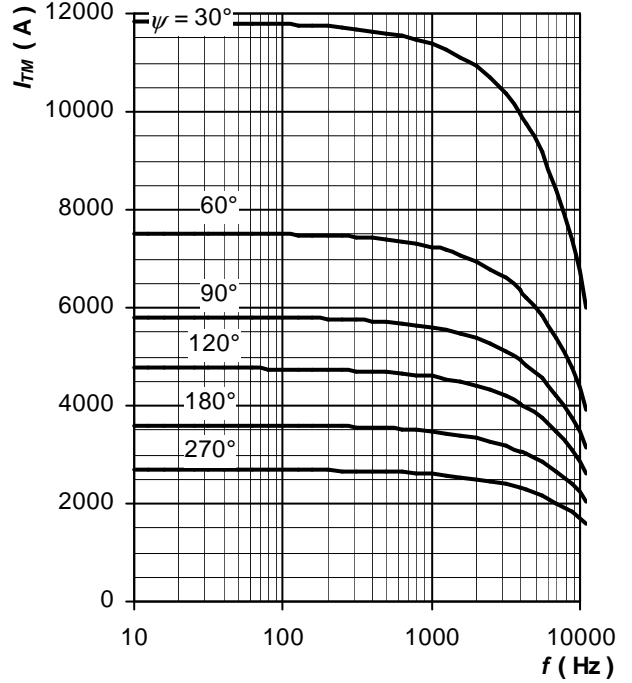


Fig. 22 Maximum on-state current vs. frequency, trapezoid waveform, $T_C = 70^\circ\text{C}$, $di_T/dt = \pm 100\text{ A}/\mu\text{s}$, $V_R = 100\text{ V}$

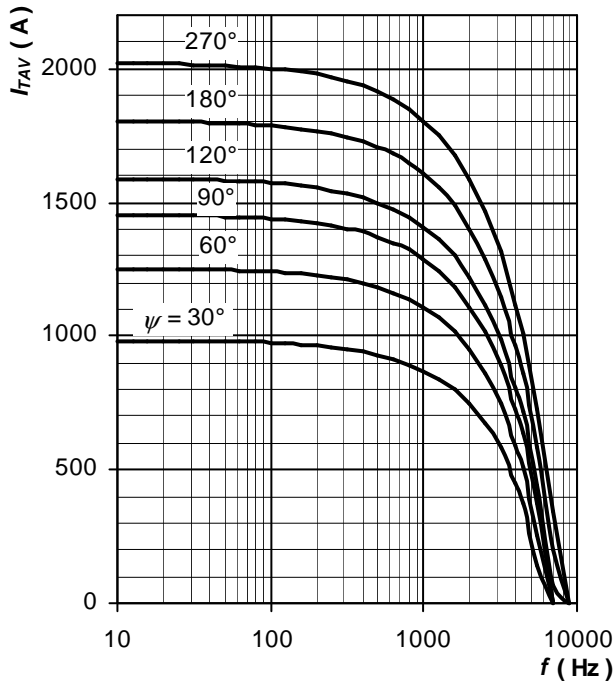


Fig. 23 Average on-state current vs. frequency, trapezoid waveform, $T_C = 70^\circ\text{C}$, $di_T/dt = \pm 100\text{ A}/\mu\text{s}$, $V_R = 2/3 V_{DRM}$

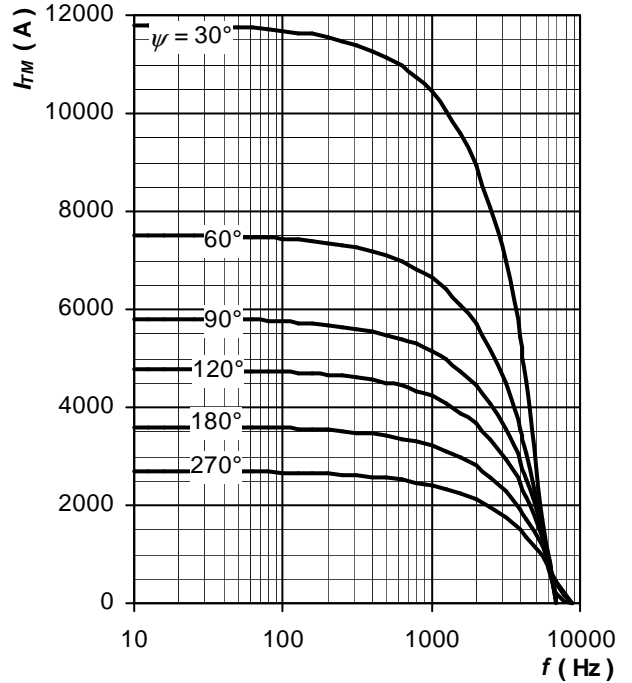


Fig. 24 Maximum on-state current vs. frequency, trapezoid waveform, $T_C = 70^\circ\text{C}$, $di_T/dt = \pm 100\text{ A}/\mu\text{s}$, $V_R = 2/3 V_{DRM}$

Frequency Ratings

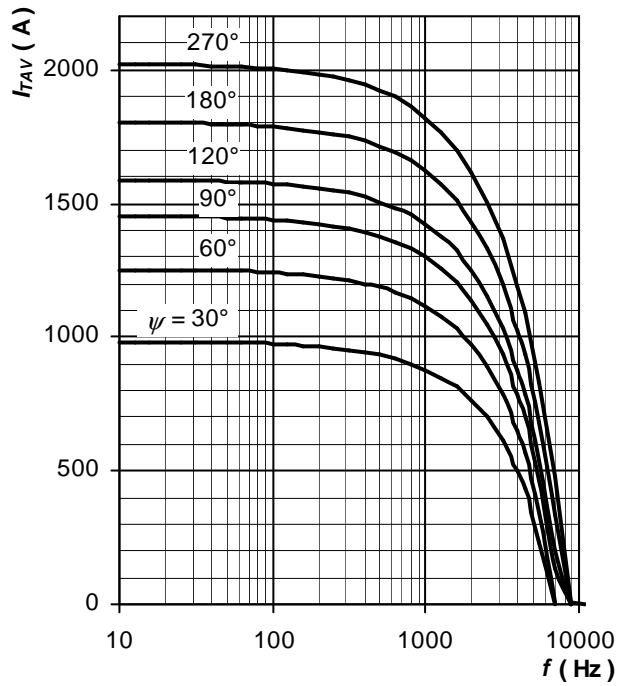


Fig. 25 Average on-state current vs. frequency, trapezoid waveform, $T_C = 70\text{ }^\circ\text{C}$, $di_T/dt = \pm 500\text{ A}/\mu\text{s}$, $V_R = 100\text{ V}$

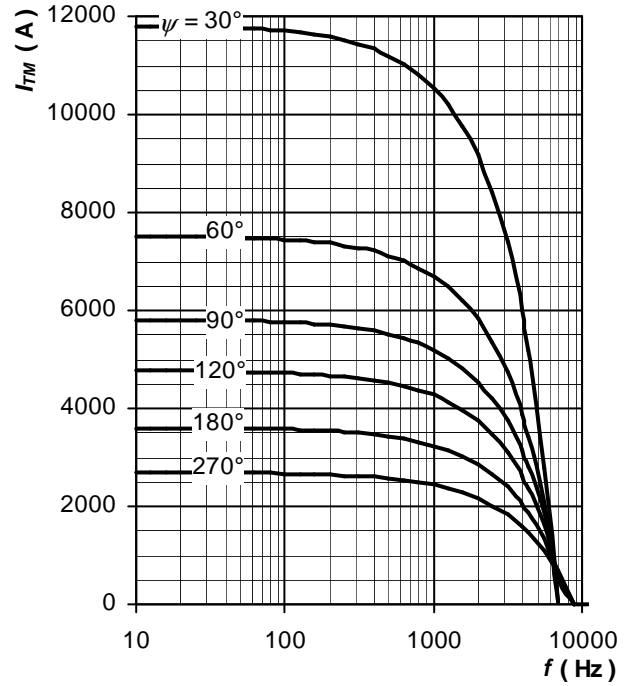


Fig. 26 Maximum on-state current vs. frequency, trapezoid waveform, $T_C = 70\text{ }^\circ\text{C}$, $di_T/dt = \pm 500\text{ A}/\mu\text{s}$, $V_R = 100\text{ V}$

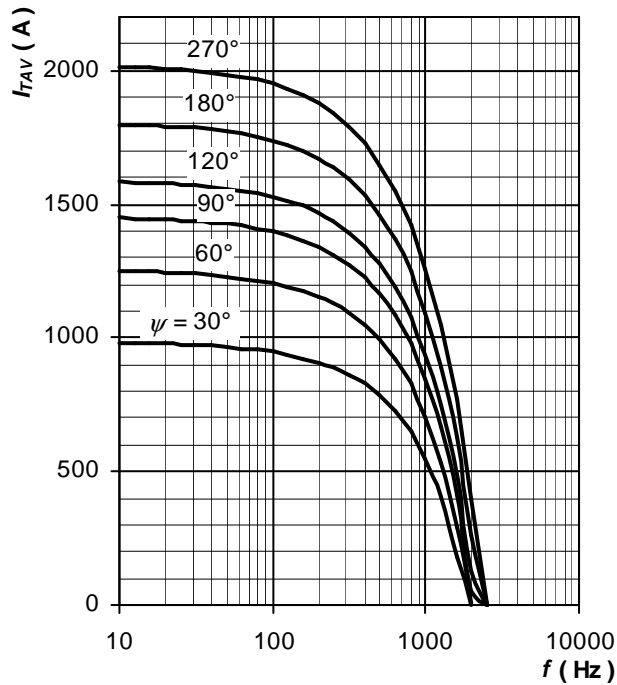


Fig. 27 Average on-state current vs. frequency, trapezoid waveform, $T_C = 70\text{ }^\circ\text{C}$, $di_T/dt = \pm 500\text{ A}/\mu\text{s}$, $V_R = 2/3 V_{DRM}$

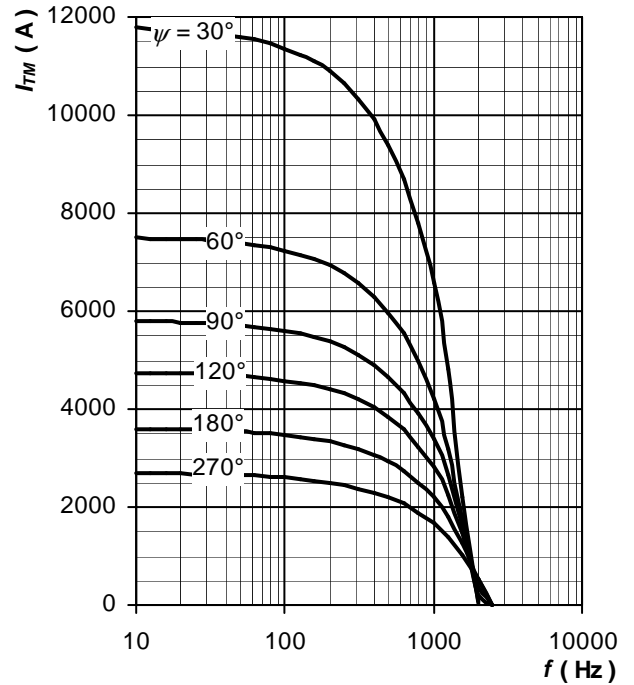


Fig. 28 Maximum on-state current vs. frequency, trapezoid waveform, $T_C = 70\text{ }^\circ\text{C}$, $di_T/dt = \pm 500\text{ A}/\mu\text{s}$, $V_R = 2/3 V_{DRM}$

Frequency Ratings

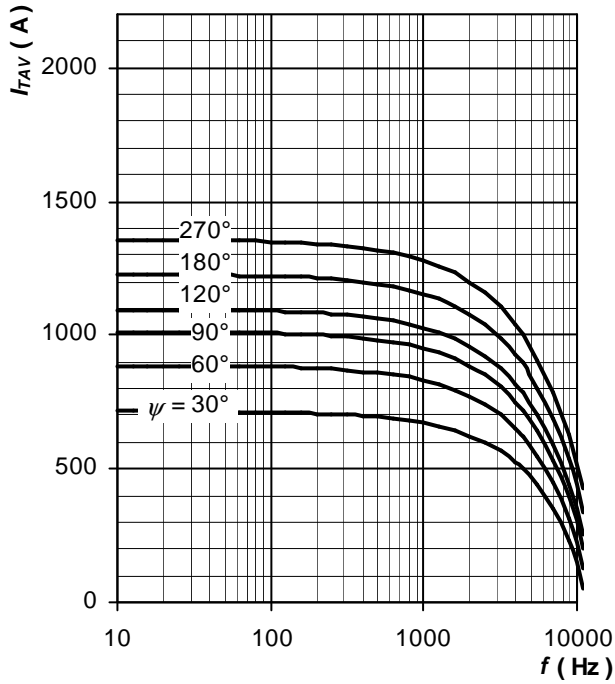


Fig. 29 Average on-state current vs. frequency, trapezoid waveform, $T_C = 90\text{ }^\circ\text{C}$, $di_T/dt = \pm 100\text{ A}/\mu\text{s}$, $V_R = 100\text{ V}$

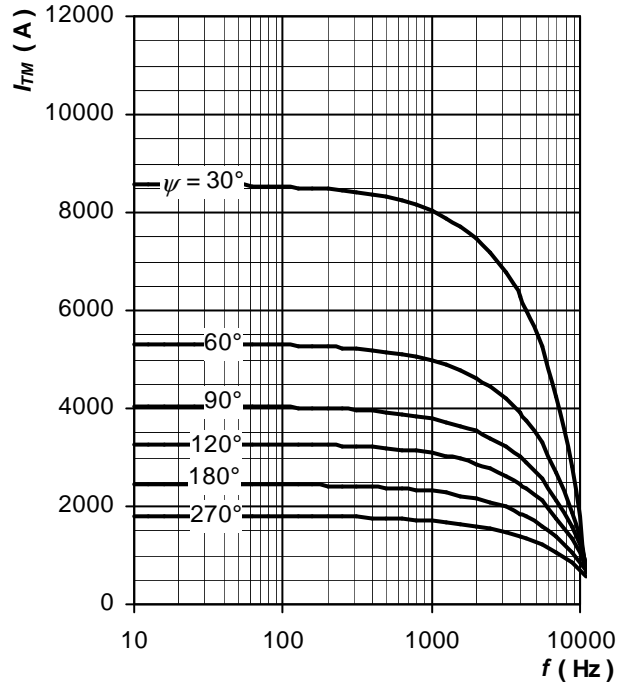


Fig. 30 Maximum on-state current vs. frequency, trapezoid waveform, $T_C = 90\text{ }^\circ\text{C}$, $di_T/dt = \pm 100\text{ A}/\mu\text{s}$, $V_R = 100\text{ V}$

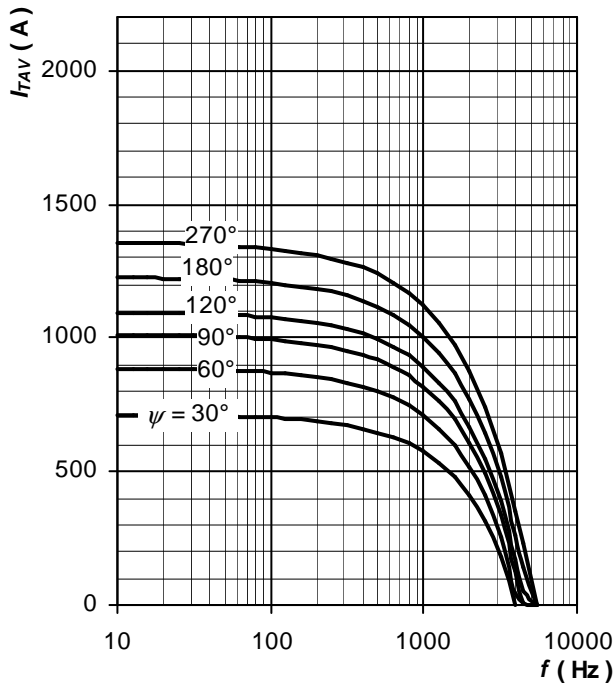


Fig. 31 Average on-state current vs. frequency, trapezoid waveform, $T_C = 90\text{ }^\circ\text{C}$, $di_T/dt = \pm 100\text{ A}/\mu\text{s}$, $V_R = 2/3 V_{DRM}$

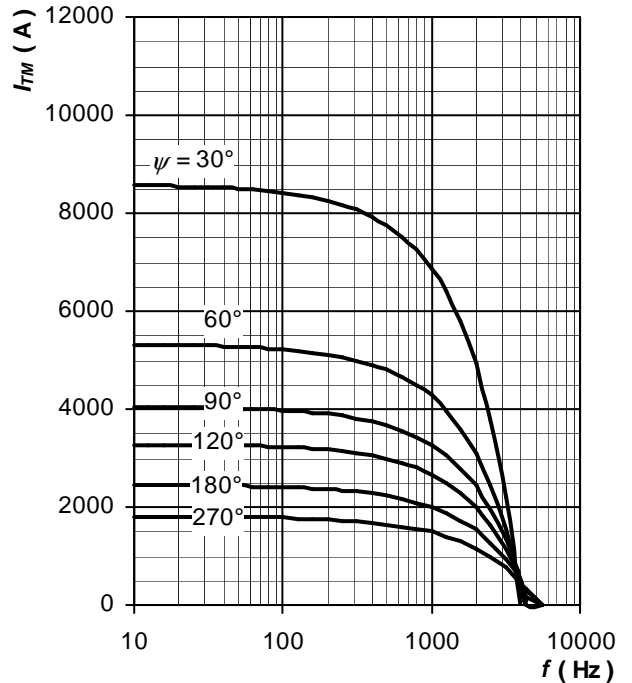


Fig. 32 Maximum on-state current vs. frequency, trapezoid waveform, $T_C = 90\text{ }^\circ\text{C}$, $di_T/dt = \pm 100\text{ A}/\mu\text{s}$, $V_R = 2/3 V_{DRM}$

Frequency Ratings

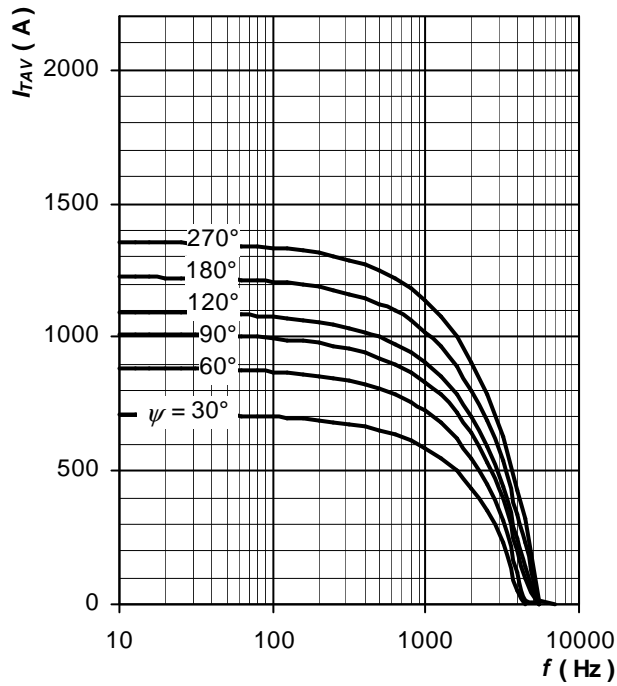


Fig. 33 Average on-state current vs. frequency, trapezoid waveform, $T_C = 90\text{ }^\circ\text{C}$, $di_T/dt = \pm 500\text{ A}/\mu\text{s}$, $V_R = 100\text{ V}$

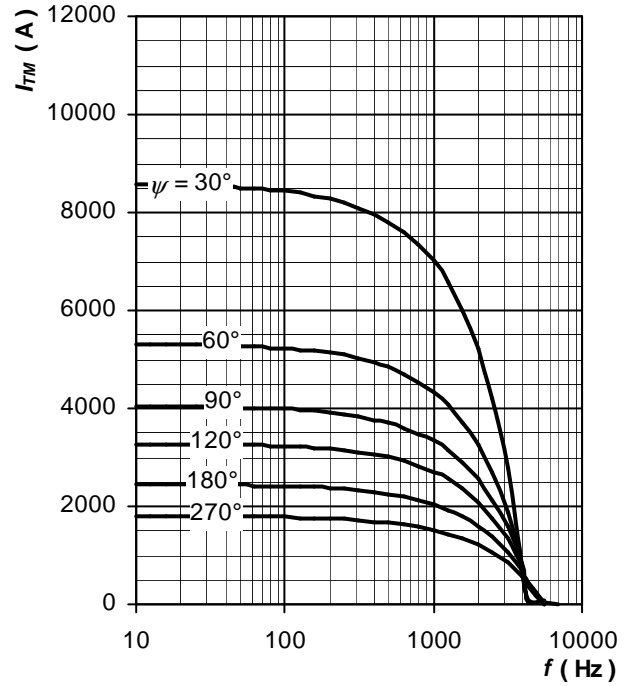


Fig. 34 Maximum on-state current vs. frequency, trapezoid waveform, $T_C = 90\text{ }^\circ\text{C}$, $di_T/dt = \pm 500\text{ A}/\mu\text{s}$, $V_R = 100\text{ V}$

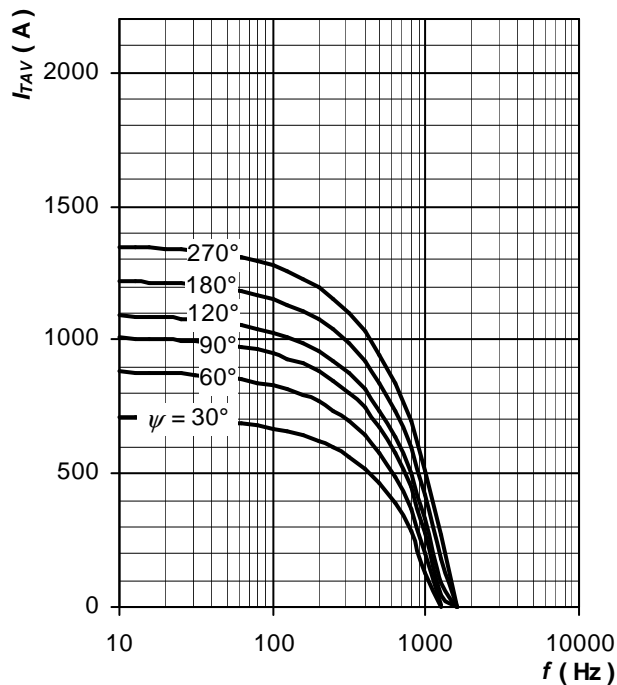


Fig. 35 Average on-state current vs. frequency, trapezoid waveform, $T_C = 90\text{ }^\circ\text{C}$, $di_T/dt = \pm 500\text{ A}/\mu\text{s}$, $V_R = 2/3 V_{DRM}$

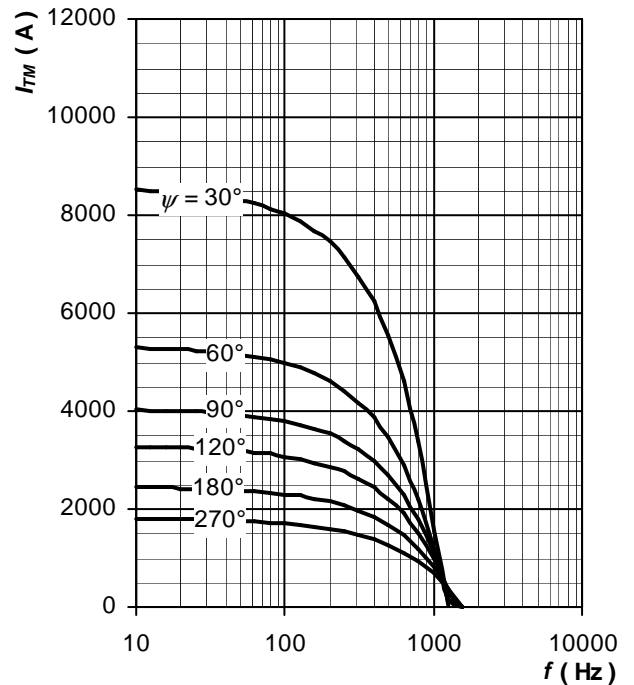


Fig. 36 Maximum on-state current vs. frequency, trapezoid waveform, $T_C = 90\text{ }^\circ\text{C}$, $di_T/dt = \pm 500\text{ A}/\mu\text{s}$, $V_R = 2/3 V_{DRM}$

Notes:

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Polovodice, a.s. reserves the right to change the data contained herein at any time without notice